Graphene Assisted Radiation Adjustable OAM Generator

Fuchun Mao¹, Ming Huang¹*, Jialin Zhang², Jingjing Yang¹, and Tinghua Li¹

Abstract—Graphene is increasingly being used in the design of electromagnetic devices. The resistivity of graphene can be adjusted via chemical potential tuning, which truly benefits the implementation of tunable and reconfigurable devices. This paper investigates the switch-like attribute of parasitic graphene surface used in a dipole operating at 0.39 THz. Further, a novel orbital angular moment (OAM) generator with radiation reconfiguration is proposed. Spiral beams carrying variety of OAM modes can be produced easily using the generator.

1. INTRODUCTION

Graphene has recently drawn massive amount of attention due to its unique semi-conductive, optical, chemical, mechanical, and thermal properties [1–3]. These features endow graphene with huge potential in various applications such as transistor [4, 5], optical modulator [6] and sensor [7]. The carrier concentration and chemical potential in graphene can be adjusted through chemical doping [8], optical injective [9], and electrostatic gating [10], which results in a tunable characteristic and makes graphene a favorite contender in electromagnetic applications from terahertz band to the visible [11]. However, current studies on graphene antenna are not yet abundant and confined to simple geometry like dipole, though a few of initial works have been presented.

The first study using graphene in antenna was presented in 2010, by adding a parasitic graphene layer between the gold arm and substrate, the authors were able to reconfigure the radiation of antenna operating at 0.12 terahertz [12]. Then, as a fundamental component in many antenna systems, the scattering, absorbance, and extinction cross section of graphene patch sticking to substrate were investigated numerically in [13]. Graphene as a real radiator rather than an auxiliary in antenna were presented in [14–16]. These antennas exploit plasmonic resonance in graphene, and allow high miniaturization, good omnidirectional radiation, as well as dynamic frequency tuning. While in [17], graphene monolayer was used as a high reactive impedance surface, and able to decrease lateral lobe. Transmission line parameters for surface plasmon polaritons (SPP) waves at graphene interface were analyzed through a tight-binding model [18, 19] and an equivalent circuit theory [20] respectively. In addition, optical antennas based on graphene rings with tunability and field enhancement in terahertz band were found by [21, 22]. These previous works are inspiring and not yet sufficient to dissuade researchers from subsequent exploring.

Considering the factor that few work has focused on the possibility of graphene to serve in an orbital angular momentum (OAM) generators who produce the so called electromagnetic vortexes from radio band to the visible, this paper is going to present a graphene assisted OAM generator, which is capable of radiation reconfiguration. The generator is composed of a circular array structure, which contains twelve independent graphene assisted dipole. All antennas and arrays are performed using the HFSS commercial electromagnetic simulation software.

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2. DIPOLE DESIGN

As a truly two-dimensional carbon crystal, graphene is described by its surface conductivity \( \sigma \), governed by the Kubo formula [23]

\[
\sigma = \frac{je^2}{\pi \hbar} \int_{0}^{\infty} \varepsilon \left[ \frac{\partial f_d(\varepsilon)}{\partial \varepsilon} - \frac{\partial f_d(-\varepsilon)}{\partial \varepsilon} \right] d\varepsilon - \frac{j e^2 (\omega - j2\Gamma)}{\pi \hbar} \int_{0}^{\infty} \frac{\partial f_d(\varepsilon)}{\partial \varepsilon} - \frac{\partial f_d(-\varepsilon)}{\partial \varepsilon} \right] d\varepsilon, \tag{1}
\]

where \( f_d(\varepsilon) = 1/\exp((\varepsilon - \mu_c)/K_B T) + 1 \) is the Feimi function, with \( K_B \) the Boltzmann’s constant, \( \mu_c \) the chemical potential, \( \varepsilon \) the energy and \( T \) the Kelvin temperature. \( \Gamma = 1/2\tau \) is a phenomenological scattering ratio with \( \tau \) the relax time. \( \hbar = h/2\pi \) is reduced Plank’s constant, \( e \) the electron charge, and \( \omega \) the radian frequency. The first term in Equation (1) denotes the intraband’s contribution to \( \sigma \), which can be computed as

\[
\sigma_{\text{intra}} = -\frac{je^2 K_B T}{\pi h(\omega - j2\Gamma)} \left\{ \frac{\mu_c}{K_B T} + 2 \ln \left[ \exp \left( \frac{\mu_c}{K_B T} \right) + 1 \right] \right\}. \tag{2}
\]

Accordingly, the second term denotes the contribution from interband, and can be evaluated as

\[
\sigma_{\text{inter}} = -\frac{je^2}{4\pi \hbar} \ln \left[ \frac{2|\mu_c| - \hbar(\omega - j2\Gamma)}{2|\mu_c| + \hbar(\omega - j2\Gamma)} \right]. \tag{3}
\]

Since the chemical potential can be adjusted by bias voltage, graphene antennas are far superior to conventional metal antenna in the aspect of reconfigurability and tenability [15, 21]. The conductivity \( \sigma \) versus frequency behavior, as well as impedance \( z \) versus frequency, is shown in Figure 1, where \( \sigma = \sigma_{\text{intra}} + \sigma_{\text{inter}} \), and \( z = 1/\sigma \), with \( T = 300 \) K and \( \Gamma = 0.11 \) meV. Obviously, the conductivity increases with chemical potential \( \mu_c \), while on the contrary the impedance decreases. More importantly, we find that resistivity of graphene is \( 49090 - j18800 \) \( \Omega \cdot m \) and \( 5.672 - j41.68 \) \( \Omega \cdot m \) at the frequencies around 0.39 THz, and the corresponding chemical potential is \( \mu_c = 1 \) meV and \( \mu_c = 0.5 \) eV, respectively.

![Figure 1](image_url)

**Figure 1.** Conductivity \( \sigma \) and impedance \( z \) versus frequency. \( \mu_c \) equals to 1 \( \mu eV \), 1 meV, 0.13 eV, 0.25 eV, 0.5 eV and 1 eV, respectively. (a) Real part of conductivity; (b) imaginary part of conductivity; (c) real part of impedance; (d) imaginary part of impedance. Illustration is a partial enlargement.
Such drastic variation will put a significant impact on the dipole performance. These two different states of graphene will be defined as “on” and “off” in what follows.

The structure of dipole is shown in Figure 2(a). Graphene monolayer with thickness 0.34 nm grows on a silica ($\varepsilon_r = 4$) substrate with thickness 0.3 $\mu$m. Gold ribbons deposit on the graphene, with thickness 2 $\mu$m. The length of dipole is $L = 0.38\lambda = 318.06\mu$m, width is $W = 10\mu$m. Gap between the two gold arms is $g = 5\mu$m. Considering an ideal scenario in aim of simulation that no material loss happen within graphene, we neglect the influence of imaginary part of impedance which indeed can be eliminated via applying the well-known impedance matching technique. The radiation patterns are shown in Figure 2(b) and Figure 2(c). The inner curve denotes the “off” state, while the outer denotes the “on” state. Obviously, the radiation differs about 50 dB both in $\varepsilon$-plane and $H$-plane. In detail, in the “on” state, the radiation efficiency is 0.634, the max gain is 0.5 dB, while in the “off” state, the radiation efficiency and max gain is respectively only $9.2 \times 10^{-6}$ and $-48$ dB. Thus the graphene film possesses a switch-like property. More importantly, when changing the chemical potential continuously, the efficiency and pattern of radiation will evolve simultaneously. On this basis, we will build a graphene assisted OAM generator in the rest of this paper.

![Graphene assisted dipole and its radiation patterns. (a) Structure diagram; (b) $\varepsilon$-plane; (c) $H$-plane.](image)

**Figure 2.** Graphene assisted dipole and its radiation patterns. (a) Structure diagram; (b) $\varepsilon$-plane; (c) $H$-plane.

### 3. GRAPHENE ASSISTED OAM GENERATOR

OAM multiplexing technology has great potential in improving spectrum efficiency and communication security [24, 25]. It is expected to become the standard transmission method in future communication system. Thus the OAM generator with EM vortexes is a research hotspot in recent years [26–33]. The model of graphene assisted OAM generator is shown in Figure 3. It’s made up of 12 radiation elements placed along a circumference equidistantly, and the space orientations of elements parallel to the $x$-axis. Geometry structure of these elements is shown in Figure 2(a). The array radius is $r_a = \lambda$, azimuthal difference between adjacent elements is $\alpha = 30^\circ$. The exciting currents express as $I_n = \exp(jl\varphi_n)$, where $l$ is the OAM mode number, and $\varphi_n = (n - 1)\alpha$ is the phase of nth element current. The array factor for such array can be written as $F_a = \sum_{l=1}^{12} \exp[j(kr_a \sin \theta \cos(\varphi - \varphi_n) + nl\alpha)]$. Apparently, the factor $F_a$
contains a phase dependent term $e^{-j\varphi}$, where $\varphi$ is the azimuth. This implies the antenna array can be used to generate spiral beams carrying OAM [27, 28]. In addition, a reflective plane about $\lambda/4$ apart from the array plane is used in simulation.

The most conspicuous feature of an OAM beam is the spiral phase structure in wave front. Figure 4 shows the distribution of phase and $H$-field intensity with OAM mode number $l = 0, 1, 2, 3, 4, 5$. Twists, at which the phase takes a sharp saltation from $\pi$ to $-\pi$, are observed in the phase panels, and the number of twists exactly equals to the OAM mode $l$. Similar rotational distributions are found in the panels of intensity. For $l = 0$, all elements are fed by the same signal without phase delay. The energy of beam emits mainly in the bore sight direction. While for $l \neq 0$, a null where the intensity of field is extremely weak will appear in the $z$ direction. The distribution of intensity expands when mode number $l$ becomes larger. Obviously, the circular dipole array radiates hollow beams with helix phase structure, and can be used as an OAM generator.

Figure 5 shows the radiation patterns in $H$-plane, where the OAM mode $l$ changes from 0 to 5, and the azimuth equals $90^\circ$. In each panel, the inner curve and outer curve are, respectively, performed at “on” state and “off” state. It can be seen that when $l = 0$, the main lobe lies at $z$ axis, perpendicular to the array plane; while for $l \neq 0$, as mentioned before, a hollow arises at the shaft axis direction, and constructs a concentric circle profile of intensity distribution. Accompanying the swell of mode number $l$, the side lobe was inhibited gradually. Another trend is the decrease of propagation length since the power radiation becomes emanative. Comparing with the “on” case, maximum gain of generator decreases about 35 dB in the “off” state. More details in this tendency can be found in Table 1. This makes it possible to obtain switch operation of OAM generator by adjusting the chemical potential via gate voltage [34].

The switch-like property of graphene in such OAM generator can be observed directly from the beam intensity distribution. For this purpose, we equidistantly set $N_f$ elements at “off” state and
Figure 5. Radiation patterns in $H$-plane when all elements are in “on” state (inner pattern), or “off” state (outer pattern), where $l$ varies from 0 to 5 in order.

Figure 6. Distribution of phase and intensity of $H$-field. Mode number is $l = 1$, the number of elements to be set at “off” state equidistantly is 6, 4, 3, 2 and 0 respectively from left to right.

analyze the field distribution. As example of $N_f = 6$, the elements with odd-number depicted in Figure 3 are selected to be set at “off”, the distance is just 1 in this case; moreover, for $N_f = 4$, elements with number 2, 5, 8 and 11 are appropriate to guarantee a distance of 2, and so on. The distribution of phase and intensity of $H$-field are plotted in Figure 6, with mode number $l = 1$. Holes of radiation can be found in intensity distribution, which exactly locate at the positions of elements at “off” state. They appear due to the huge difference of element radiation between “on” and “off” state.
Figure 7. 2-D and 3D radiation patterns of generator, with mode number $l = 0$, and chemical potential $\mu_c = 1$ meV, 100 meV and 500 meV.

Table 1. Radiation efficiency and max gain under different chemical potential.

<table>
<thead>
<tr>
<th>$l$</th>
<th>$\mu_c$</th>
<th>1 meV</th>
<th>1.5 meV</th>
<th>2 meV</th>
<th>0.1 eV</th>
<th>0.5 eV</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>$\eta$</td>
<td>0.7976</td>
<td>0.4151</td>
<td>0.3378</td>
<td>0.0048</td>
<td>0.00035</td>
</tr>
<tr>
<td></td>
<td>$G_{\text{max}}$</td>
<td>38.5</td>
<td>20.153</td>
<td>16.506</td>
<td>0.2368</td>
<td>0.01702</td>
</tr>
<tr>
<td>1</td>
<td>$\eta$</td>
<td>0.8083</td>
<td>0.4236</td>
<td>0.3448</td>
<td>0.0048</td>
<td>0.00034</td>
</tr>
<tr>
<td></td>
<td>$G_{\text{max}}$</td>
<td>15.908</td>
<td>8.0317</td>
<td>6.5164</td>
<td>0.0994</td>
<td>0.00728</td>
</tr>
</tbody>
</table>

In addition, the phase structure appears distortion, which will vanish if all elements operating at the same condition. In fact, graphene ribbons can further utilized in gain control within large region, which is testified by Table 1 and Figure 7.

4. CONCLUSIONS

Firstly, the conductivity and resistivity of graphene are analyzed near 0.4 terahertz. Then we design a graphene assisted dipole antenna by adding a graphene monolayer between the silicon substrate and gold radiator. Simulation results shown that the graphene layer demonstrates a switch-like property. When the chemical potential is low, $\mu_c = 1$ meV for instance, the impedance of graphene film will be extremely high and reaches a $10^5 \Omega \cdot m^{-1}$, at which the dipole radiates normally. While the chemical potential is high, such as $\mu_c = 0.5$ eV, the impedance of graphene layer is only about $5.7 \Omega \cdot m^{-1}$, and the radiation is weak and equivalent to be shut down. Finally, a circular antenna array is proposed to produce OAM beams. The radiation pattern of the generator are reconfigurable via chemical potential adjusting.
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